

PUMB10,115 Datasheet





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DiGi Electronics Part Number PUMB10,115-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number PUMB10,115

Description TRANS PREBIAS 2PNP 50V 6TSSOP

Detailed Description Pre-Biased Bipolar Transistor (BJT) 2 PNP - Pre-Bias ed (Dual) 50V 100mA 180MHz 300mW Surface Mou

nt 6-TSSOP



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
PUMB10,115	Nexperia USA Inc.
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
2 PNP - Pre-Biased (Dual)	100mA
Voltage - Collector Emitter Breakdown (Max):	Resistor - Base (R1):
50V	2.2kOhms
Resistor - Emitter Base (R2):	DC Current Gain (hFE) (Min) @ Ic, Vce:
47kOhms	100 @ 10mA, 5V
Vce Saturation (Max) @ lb, lc:	Current - Collector Cutoff (Max):
100mV @ 250μA, 5mA	100nA
Frequency - Transition:	Power - Max:
180MHz	300mW
Grade:	Qualification:
Automotive	AEC-Q101
Mounting Type:	Package / Case:
Surface Mount	6-TSSOP, SC-88, SOT-363
Supplier Device Package:	Base Product Number:
6-TSSOP	PUMB10

Environmental & Export classification

8541.21.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



PUMB10

50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = 47 k Ω

30 March 2023

Product data sheet

1. General description

PNP/PNP double Resistor-Equipped Transistor (RET) in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

NPN/PNP complement: PUMD10 NPN/NPN complement: PUMH10

2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- · Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

3. Applications

- Low current peripheral driver
- Controlling IC inputs
- · Replaces general-purpose transistors in digital applications

4. Quick reference data

Table 1. Quick reference data

		Table 1. Quick reference data					
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
V _{CEO}	collector-emitter voltage	open base		-	-	-50	V
Io	output current			-	-	-100	mA
R1	bias resistor 1 (input)			1.54	2.2	2.86	kΩ
R2/R1	bias resistor ratio			17	21	26	



50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = 47 k Ω

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	l1	input (base) TR1		
3	O2	output (collector) TR2	<u> </u>	R1 R2
4	GND2	GND (emitter) TR2		TR2
5	12	input (base) TR2		
6	01	output (collector) TR1	☐1 ☐2 ☐3 TSSORG (SOT363)	
			TSSOP6 (SOT363)	GND1 I1 O2
				006aaa212

6. Ordering information

Table 3. Ordering information

Type number	Package	Package				
	Name	Version				
PUMB10		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	<u>SOT363</u>			

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PUMB10	B%0

[1] % = placeholder for manufacturing site code

50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = 47 k Ω

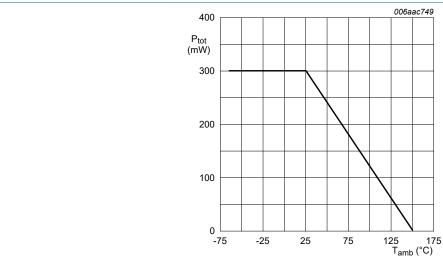
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit		
Per transiste	Per transistor							
V_{CBO}	collector-base voltage	open emitter		-	-50	V		
V_{CEO}	collector-emitter voltage	open base		-	-50	V		
V _{EBO}	emitter-base voltage	open collector		-	-5	V		
VI	input voltage			-12	5	V		
Io	output current			-	-100	mA		
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW		
Per device								
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	300	mW		
Tj	junction temperature			-	150	°C		
T _{amb}	ambient temperature			-65	150	°C		
T _{stg}	storage temperature			-65	150	°C		

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.



FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint

Fig. 1. Per device: Power derating curve

50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = 47 k Ω

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	417	K/W

[1] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint.

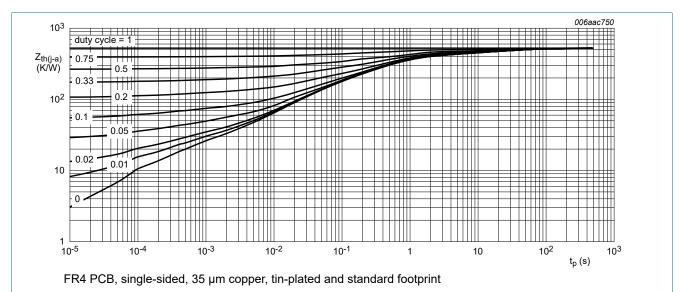


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 2.2 kΩ, R2 = 47 kΩ

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						
V _{(BR)CBO}	collector-base breakdown voltage	$I_C = -100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$		-50	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	$I_C = -2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-50	-	-	V
I _{CBO}	collector-base cut-off current	V _{CB} = -50 V; I _E = 0 A; T _{amb} = 25 °C		-	-	-100	nA
I _{CEO}	collector-emitter cut-off	V _{CE} = -30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	-100	nA
current		V _{CE} = -30 V; I _B = 0 A; T _j = 150 °C		-	-	-5	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	-180	μΑ
h _{FE}	DC current gain	V_{CE} = -5 V; I_{C} = -10 mA; T_{amb} = 25 °C		100	-	-	
V _{CEsat}	collector-emitter saturation voltage	I _C = -5 mA; I _B = -0.25 mA; T _{amb} = 25 °C		-	-	-100	mV
V _{I(off)}	off-state input voltage	V_{CE} = -5 V; I_{C} = -100 μ A; T_{amb} = 25 °C		-	-0.6	-0.5	V
V _{I(on)}	on-state input voltage	V_{CE} = -0.3 V; I_{C} = -5 mA; T_{amb} = 25 °C		-1.1	-0.75	-	V
R1	bias resistor 1 (input)			1.54	2.2	2.86	kΩ
R2/R1	bias resistor ratio			17	21	26	
C _c	collector capacitance	/ _{CB} = -10 V; I _E = 0 A; i _e = 0 A; = 1 MHz; T _{amb} = 25 °C		-	-	3	pF
f _T	transition frequency	V_{CE} = -5 V; I_{C} = -10 mA; f = 100 MHz; T_{amb} = 25 °C	[1]	-	180	-	MHz

[1] Characteristics of built-in transistor

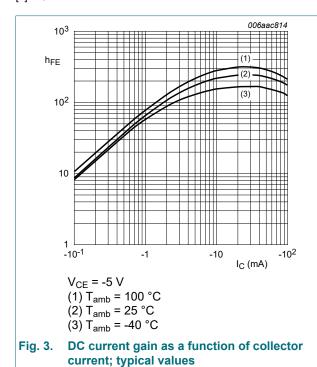
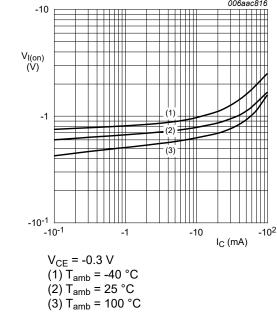


Fig. 4. Collector-emitter saturation voltage as a function of collector current; typical values

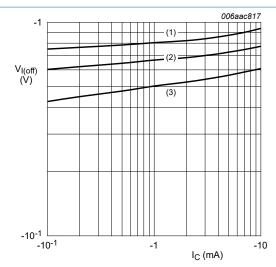
50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = 47 k Ω



$$(1) T_{amb} = -40 °C$$

(2)
$$I_{amb} = 25 \,^{\circ}C$$





$$V_{CE} = -5 V$$

$$(1) T_{amb} = -40 °C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

V_{CE} = -5 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C

Off-state input voltage as a function of collector current; typical values

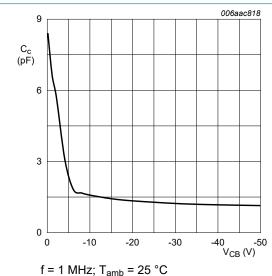


Fig. 7. Collector capacitance as a function of collectorbase voltage; typical values

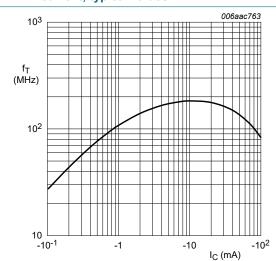


Fig. 8. Transition frequency as a function of collector current; typical values of built-in transistor

50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = 47 k Ω

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

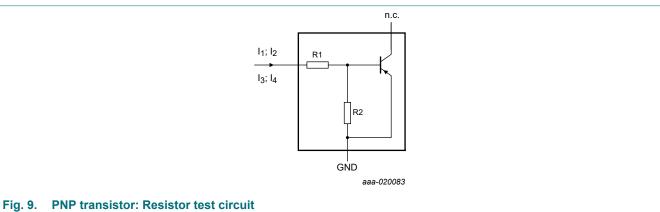
Resistor calculation

· Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$



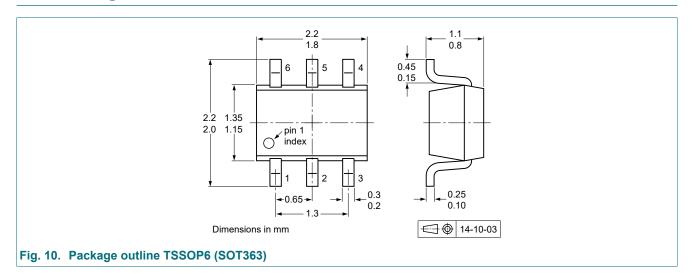
Resistor test conditions

Table 8. Resistor test conditions

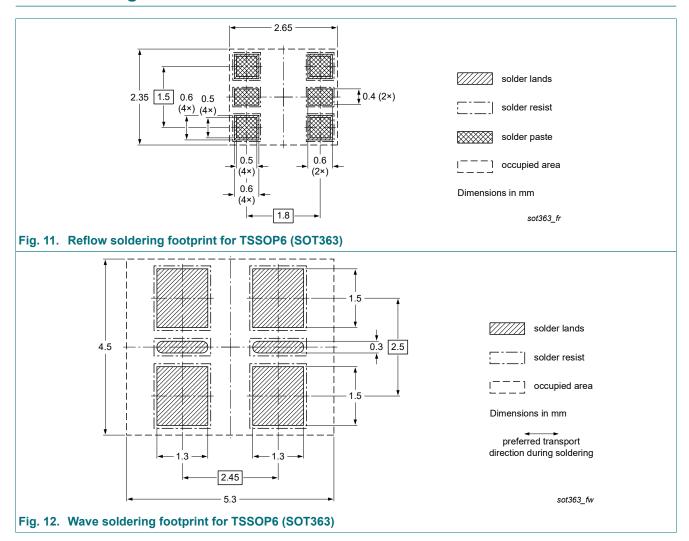
Type number	R1 (kΩ)	R2 (kΩ)	Test conditions	Test conditions		
			I ₁	l ₂	l ₃	14
PUMB10	2.2	47	-90 µA	-140 µA	55 µA	105 μΑ

50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = 47 k Ω

12. Package outline



13. Soldering



50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = 47 k Ω

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PUMB10 v.4	20230330	Product data sheet	-	PEMB10_ PUMB10 v.3
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Family data sheet reduced to single type data sheet. Packing information is removed. 			
PEMB10_ PUMB10 v.3	20120103	Product data sheet	-	PEMB10_ PUMB10 v.2
PEMB10_ PUMB10 v.2	20031003	Product data sheet	-	PEMB10 v.1
PEMB10 v.1	20010914	Preliminary specification	-	-

50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = 47 k Ω

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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PUMB10

50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = 47 k Ω

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